arXiv:cond-mat/9708031v1 5 Aug 1997

Derivation of symmetry-based pseudo spinmodels for modulated materials

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(M arch 23, 2024)

A general concept for the derivation of sym metry-based pseudo spin H am iltonians is described. It system atically bridges the gap between the atom istic basis and various pseudo spin models presented in literature. It thus allows the application of the multitude of analytical and numerical procedures derived for the statistical mechanics treatment of the latter to the description of structurally modulated crystals and furnishes a general frame for reviewing these models from a common point of view.

I. IN TRODUCTION

Various approaches for the description of systems exhibiting commensurately and/or incommensurately structurally modulated phases were presented in the literature: Landau-type models^{1;2}, the model of Chen and W alker^{3;4} for A₂BX₄-compounds and betaine calcium chloride dihydrate (BCCD), the model of H linka et al.⁵ for BCCD, other microscopic models with continuous local variables like the DIFFOUR (discrete ⁴) models⁶ and pseudo spin models like the ANNNI (axial next nearest neighbor Ising)^{7;8}, AANNDI (axial antisymmetric nearest neighbor double Ising)⁹ and DIS (double Ising spin)^{10;11} models. Ab initio and molecular dynamics (MD) investigations^{12;13} allow to gain insight into processes and interactions on an atom istic level.

A comparative analysis of the merits and shortcom ings of these models is facilitated and system atized by the developm ent of a general procedure for the form ulation of m odel H am iltonians for uniaxially structurally modulated compounds. Such a procedure is described in this paper. It is based on the discrete arrangement of atom s and m akes use of the sym m etry of the lattice. It leads to a hierarchy of Ham iltonians corresponding to di erent approximations, that describe, among others, the di erent microscopic models mentioned above. These can thus be discussed from a common point of view. The models are obtained by identication of the relevant variables and speci cation of the respective couplings. Their Ham iltonians allow both num erical and approximate analytical treatments. One advantage of such atom istic sym m etry-adapted m odel H am iltonians is that they allow predictions also on complicated phase diagram s containing long-period structures, on their space group symmetries, and on phase transitions which are not accessible by ab initio and MD calculations. Previously it was considered a weak spot, especially of pseudo spin models, that the signi cance (on an atom istic scale)

of the m odel (pseudo spin) variables was not well de ned and that predictions in terms of space group symmetries could not be m $ade^{3;14}$.

II.FORM ULATION IN TERMS OF SYM METRY -ADAPTED LOCAL MODES

The basis of the procedure is to start from symmetryadapted bcalm odes (SALM s) as a bcalized basis set for the expansion of atom ic displacements in properly chosen crystallographic (sub)cells. This facilitates the incorporation of both the discreteness of the lattice and the overall symmetry of the crystal. The relevant SALM s can either be determined by rst-principles calculations or taken from the observed displacements at the phase transitions. Generalized local variables de ned in terms of the amplitudes of these SALM s serve as variables for a microscopic H amiltonian. This procedure stresses the atom istic roots of the models, leads to models conform – ing to lattice symmetry and facilitates the prediction of spontaneous polarizations of modulated phases and of the displacements occuring at structural transitions.

Let the crystal be composed of N unit cells with K particles each (of which K⁰ are non equivalent). The crystal is described by a 3K N -dimensional con guration vector $\underline{R} = \underline{R}_0 + \underline{R}$, whose entries specify the average positions of the atom s. \underline{R}_0 describes a T - and p-dependent reference structure which is invariant under all elements G = fR jg of the norm al phase space group G_0 . The sym m etry-breaking displacement \underline{R} is zero in the normal phase. In the lower sym m etry phases (unm odulated or com m ensurately or incom m ensurately m odulated), it can be written as a superposition

$$\underline{R} = \underbrace{R}_{n} \underline{R}_{n}$$
(1)

of local contributions \underline{R}_n having non-zero entries for only those atom swhich are associated to cell n.

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 \underline{R}_n is expanded in terms of a local basis set. If the set re lects the crystal symmetries, it is su cient in most cases to retain only a few (e.g. one or two) localmodes. The smallest unit in the crystal with respect to symmetry is the asymmetric unit A_0^1 of the space group G_0 . Symmetry imposes no restrictions on the positions of the K 0 atom s associated to this polyhedral subcell (nor need they to be known except for a quantitative atom istic determ ination of model parameters). Further subcells A_n^i dened by

$$A_0^i = G^i A_0^1$$
 and $A_n^i = fE jng A_0^i$

cover the whole crystal. The B = $[G_0:T]$ space group operations $G^1; \ldots; G^B$ are coset representatives in a coset decomposition of G_0 with respect to its subgroup T of primitive translations. They have to be chosen such that the subcells $A_n^1; \ldots; A_n^B$ form a contiguous new choice of cell n. The basis set of 3K 0 subcell modes \underline{V}_n^i ; = 1; $\ldots; 3K \,^0$ for the displacements of the K 0 atoms associated with A_n^i should satisfy the relation $\underline{V}_n^{i^0} = G \underline{V}_n^i$, where G 2 G_0 is the space group operation transforming A_n^i into $A_{n^0}^{i^0}$. It is thus entirely determined by the choice of modes in the asymmetric unit A_0^1 .

A complete { for K $^{0}B > K$ over-complete (see below) { set of 3K $^{0}B N$ localm odes can be constructed as linear combinations

$$\underline{W}_{n}^{\mathrm{I}} = \sum_{i=1}^{X^{\mathrm{B}}} S^{\mathrm{I}i} \underline{V}_{n}^{i}$$
(2)

of the modes in subcells i = 1; :::; B with a B B m atrix <u>S</u>. The subset $f\underline{W}_{n}^{I}$: = 1;:::;3K ⁰g is called the Ith set of SALM s for celln. The transform ation m atrix S should be chosen in accordance with the irreducible representations (IR s) of the point group ${f \$}_0$ such that for the construction of every symmetry mode (deformation \underline{R} transforming according to an \mathbb{R} of the group G (q) of the wave vector) only a minimum of di erent sets of SALMs is needed. Localmodes \underline{W}_{n}^{I} and \underline{W}_{m}^{I} describe the same displacem ent patterns in their respective cells, i.e. $\underline{W}_{m}^{I} = fE jm ng \underline{W}_{n}^{I}$. All linear combinations of displacem ent vectors in one set of SA LM s have the sam e transform ation behavior, which is entirely determ ined by S, since, apart from a prim itive translation, an arbitrary space group operation only permutes the subcell indices. Only those sets of SALM s can contribute to the deformation \underline{R} that have the symmetry properties in posed by the IR according to which \underline{R} transform s.

A tom s on special positions (faces, edges and corners of the subcells) cause the num ber $3K \ ^0B N$ of local modes to be higher than the num ber $3K \ N$ of independent displacements. Hence, the coe cients of an expansion in terms of these SALM s have to satisfy consistency relations.

The symmetry-breaking displacement \underline{R}_n in cell n is decomposed into contributions \underline{R}_n^{I} from the B sets of SALM s:

$$\underline{\mathbf{R}}_{n} = \underbrace{\mathbf{R}}_{\mathbf{I}=1}^{\mathbf{X}} = \underbrace{\mathbf{R}}_{n}^{\mathbf{I}} = \underbrace{\mathbf{R}}_{n}^{\mathbf{I}} = \underbrace{\mathbf{R}}_{n}^{\mathbf{I}} \underbrace{\mathbf{M}}_{n}^{\mathbf{I}} :$$
(3)

Under a change of external parameters, \underline{R}_n will follow a valley of low local potential (see below) in the high-dimensional conguration space corresponding to the modes relevant for the phase transitions. In the sim – plest and frequent case this valley is not very shallow and the contribution $\underline{R}_n^{I} = \int_{=1}^{P} a_n^{I} \underline{W}_n^{I}$ from the Ith set of SALM s will lie on a curve (dimension $d_a = 1$). In a

m ore general case, \underline{R}_n^{T} will lie on a d_a 3K ⁰-dimensional curved surface . This generalization would account for deviations due to dierent (sm all) external elds and allow the treatment of additional uctuations (about the bottom of the valley) described by the additional d_a 1 m odes. The special form of the sym metry-breaking displacement (in the asymmetric unit A_0^1) connected with the transitions is not determined by space group symmetry. It will, in general, be dierent even for materials exhibiting the same symmetries of the normal and the modulated phases (e.g. A_2BX_4 compounds). One introduces local sets of a coordinate transformation $a_n^{T} = f^{T} (Q_n^{TI}; :::;Q_n^{TISK}); = 1; :::;3K^0$ leading to

$$\underline{R}_{n}^{\mathrm{I}}(\mathbb{Q}_{n}^{\mathrm{I}}; \ldots; \mathbb{Q}_{n}^{\mathrm{I}}; \mathbb{Q}_{n}^{\mathrm{I}}) = \int_{=1}^{\mathbb{X}^{\mathsf{K}^{0}}} f^{\mathrm{I}}(\mathbb{Q}_{n}^{\mathrm{I}}; \ldots; \mathbb{Q}_{n}^{\mathrm{I}}; \mathbb{X}^{0}) \underline{W}_{n}^{\mathrm{I}}$$

such that is parametrized by the rst d coordinates (relevant variables per set of SALM s).

The space group and the direction of the modulation determ ine the subcell generators G^1 ;:::; G^B and the matrix \underline{S} and thus should be the same for a whole class of materials. On the other hand, the displacements of atoms in the asymmetric unit and the coordinate transformations f^I are determined by the local potential and thus by the speci c material under investigation. This allows a separation of e ects of crystal symmetry from e ects characteristic for a special substance.

The symmetry-adaptation (2) provides a two-way relationship between the B sets of SALMs and the IRs of G (q): 1) In the superposition (3), a symmetry mode <u>R</u> transforming according to a given IR requires the inclusion of a few distinct sets of SALMs (e.g. $I = 1; :::; d_s$) and the exclusion of the others. 2) The included sets, on the other hand, may lead, with di erent spatial modulations of the respective relevant local variables $Q_n^{II}; :::; to$ displacements transforming according to di erent (but in general not all) IR s.

In the simplest case { one relevant set of SALM s ($d_s = 1$) and one degree of freedom in the asymmetric unit ($d_a = 1$) { expansion (1) simplines to

$$\underline{\mathbf{R}} = \sum_{n}^{\mathbf{X}} \underline{\mathbf{R}}_{n}^{1} (Q_{n}^{11}; 0; \dots; 0)$$

and the num ber of variables per unit cell is reduced from 3K to 1 (Q $_{\rm n}^{11}$).

III. DER IVAT ION OF M ICROSCOPIC SYM METRY - ADAPTED HAM ILTON IANS AND RELATION TO OTHER MODELS

The potential is expanded in a power series of the Q_n^{I} . The terms containing only variables with given n form the local potential $loc(Q_n^{11}; :::;Q_n^{B};^{3K})$ for cell n. The general H am iltonian of the system is then

$$H = \begin{pmatrix} 2 & 3 \\ X & X \\ 4 & P_n^{I} & 2 + \log (Q_n^{11}; \dots; Q_n^{B}; 3K^{\circ}) \\ & & I; \\ & + \inf (\dots; Q_n^{I}; \dots; Q_m^{J}; \dots; Q_m^{J}; \dots); \end{pmatrix}$$

where P_n^{I} is the momentum conjugate to Q_n^{I} . A veraging out all irrelevant generalized coordinates by taking the trace over variables I \in 1; \in 1 yields an elective H am iltonian

$$\overline{H} = tr(H) = \sum_{n=1}^{n} P_{n}^{11} + \sum_{n=1}^{n} P_{n}^{11} + \sum_{n=1}^{n} (Q_{n}^{11})^{1}$$
(4)
+
$$-int (:::;Q_{n}^{11};:::;Q_{m}^{11};:::):$$

In the case of two relevant sets of SA LM s per cell ($d_s = 2$; I = 1;2), one gets the two-variable version

$$\overline{H} = X h P_n^{11} + P_n^{21} + -loc} (Q_n^{11}; Q_n^{21})^{i}$$

$$+ -int (:::; Q_n^{11}; Q_n^{21}; :::; Q_m^{11}; Q_m^{21}; :::):$$

A form with the superscript 21 replaced by 12 is obtained in the case of one relevant set of SALM s per cell ($d_s =$ 1; I = 1) but two relevant generalized coordinates ($d_a =$ 2) per asymmetric subcell.

The total num ber of relevant variables per cell is $d_a \quad d_a$. The local potential and the interaction potential are e ective potentials. Due to the therm all averaging over the irrelevant variables, they depend, by their very de nition, directly on temperature and stresses (which both determ ine the strains). U sually -loc and -int are expanded up to forth and second order respectively and only interactions between rst, second and third nearest neighbors are kept.

The Hamiltonian (4) models only the symmetrybreaking contribution per cell. The totally symmetric IR of G_0 , which also contributes to the displacements, is always present but has been absorbed into the atom positions of new reference states, which can be viewed (for the whole range of T and p) as (unstable) norm alphase con gurations.

Form odulated crystals with norm alphase space group $G_0 = P nm a$ exhibiting a pseudoperiodicity along the direction of modulation, half cells instead of crystallographic unit cells m ay be chosen. The H am iltonian (4) corresponds to a version of the DIFFOUR model with one degree of freedom per lattice site, or to the ANNNI model. The case where two local modes (per half cell) with di erent transform ation behavior $(d_{g} = 2)$ are incorporated corresponds to Chen and W alker's model or to the D IS model. A ssum ing, in addition, two relevant (d_a = 2) generalized variables Q $_{n}^{11}$ and Q $_{n}^{12}$ for each of the two relevant sets of SALM s, one arrives at a model corresponding to a version of the DIFFOUR model with four degrees of freedom per lattice site. If Q_n^{11} and Q_n^{12} are assumed to describe only displacements of the betaine and CaCl groups respectively, the model discussed in refs.^{5;15} for BCCD is obtained.

IV. IN TRODUCTION OF THE PSEUDO-SPIN FORMALISM

Space group operations can be considered to transform the generalized variables Q_n^p instead of the modes \underline{W}_n^p [p = (I)]. The local potential may have equivalent minim a: if there is a minimum at a certain set of the variables Q_n^p then every space group operation which transforms a cell into itself but changes the conguration Q_n^p generates another equivalent minimum. A further simplic cation may then be introduced by projecting the remaining continuous generalized local variables

$$Q_{n}^{p} = D_{n}^{p} j_{n}^{p} j_{n}^{p} = D_{n}^{p} j_{n}^{p} j_{n}^{p}$$
 (5)

onto two-valued pseudo spin variables n p p representing their signs. Because they assume only the values + 1 or

1, they are called pseudo spins. They should not be confused with usual spins nor are they localized at a definite position in the cell. A switch of $\frac{p}{n}$ from +1 to 1 or vice versa corresponds to a transition from one well to another and is connected with a collective motion of all particles in the unit according to the corresponding SALM \underline{W}_{n}^{p} . The motion in a single well as described by \mathfrak{D}_{n}^{p} joccurs on a much shorter timescale and can therefore be averaged out. The interactions (expanded up to second order in \mathfrak{Q}_{n}^{p}) are replaced by the averages over single wells (taken separately for every \mathfrak{D}_{n}^{p}):

$$\begin{array}{cccc} pq & \hline \mathbf{j}_{\mathbf{A}}^{\mathbf{p}} \mathbf{j} & \hline \mathbf{j}_{\mathbf{A}}^{\mathbf{q}} \mathbf{j} & p & q \\ nm & \mathbf{j}_{\mathbf{A}}^{\mathbf{p}} \mathbf{j} & \hline \mathbf{j}_{\mathbf{A}}^{\mathbf{q}} \mathbf{j} & n & m \\ \end{array} = : \mathbf{J}_{nm}^{pq} p q;$$

with couplings $J_{nm}^{pq} = \frac{pq}{nm}$ $\frac{p}{p}$ j. Since the latter are de ned as therm al averages, they depend inherently on external parameters. The procedure yields the follow – ing pseudo spin H am iltonian:

$$H = \frac{1}{2} X X_{nm \ n \ m} J_{nm \ n \ m}^{pq} P :$$
(6)

Special systems discussed along these lines were the ANNNIm odel (one relevant mode per unit) or the D IS model (two variables)^{16;17}. Symmetry considerations yield conditions for the dependence of the potential on the generalized variables, which have for example been taken into account when formulating the AANNDI⁹ or the D IS¹⁰ m odel.

V.SYM M ETRY OF THE STRUCTURAL M ODULATION

Directly below the transition temperature from the unm odulated high temperature phase to the modulated phases a sinusoidal structural modulation is formed, which can be described by a Bloch mode of distinct symmetry (symmetry mode). Upon further cooling, it becomes more and more rectangular. Thus higher harmonics or further symmetry modes need to be considered. In good approximation, the relative displacements in one unit (cell or half cell) do not change whereas the amplitudes vary from unit to unit. This enters in the present approach by using restricted (e.g. one mode) bcaldisplacements (SALM s) and modeling the sinusoidal modulation and deviations from it by a variation of the amplitudes of the SALM s.

The local displacements are determined by the local potentials; hence the relevant SALMs and the respective coupling parameters can be determined for example by ab initio-type calculations. W ith the methods of statistical mechanics, the resulting H am iltonians yield the stable proles of the model variables. The superpositions of SALMs described by these proles correspond to a mixture of a few symmetry modes. Just below the norm all phase, where the prole is nearly sinusoidal, the primary contribution to the structural deformation of the crystal transforms according to an IR of G(q).

VI.CONCLUSIONS

Symmetry-adapted localmodes de ned for crystallographic (sub) cells represent a natural lattice theoretical basis for the form ulation of model H am iltonians for describing m odulated system s. Sym m etry considerations in term s of the group of the m odulation vector lead to the selection of adm issible localm ode com binations. By well de ned therm alaveraging, the lattice theoretical system s can be projected onto corresponding pseudo spin models. The coupling constants of the latter depend, by their very de nition, on tem perature and strains. Explicit calculations along these lines would allow, for not too com plicated system s, to go all the way from an atom istic theory to explicit statem ents on phase diagram s, polarizations etc. In such a treatment approximations are of course necessary and should be made (in the original atom istic theory as well as in the consecutive model calculations); but one should avoid ad hoc assumptions (ts) as far as possible.

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